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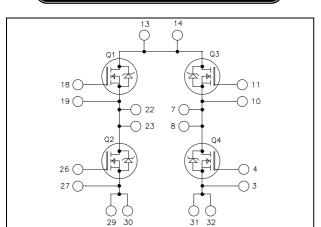


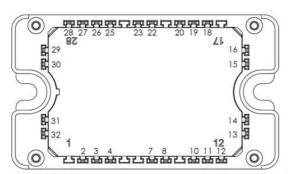






Full - Bridge Super Junction MOSFET Power Module





All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

$$\begin{split} V_{DSS} &= 800V \\ R_{DSon} &= 150 m\Omega \text{ max @ Tj} = 25^{\circ}C \\ I_D &= 28A \text{ @ Tc} = 25^{\circ}C \end{split}$$

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Super junction MOSFET
 - Ultra low R_{DSon}
 - Low Miller capacitance
 - Ultra low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS Compliant

All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (per super junction MOSFET)

Symbol	ol Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Voltage		800	V
I_D	(Continuous I)rain (Current	$T_c = 25$ °C	28	
		$T_c = 80$ °C	21	A
I_{DM}	Pulsed Drain current		110	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		150	mΩ
P_D	Power Dissipation $T_c = 25^{\circ}C$		277	W
I_{AR}	Avalanche current (repetitive and non repetitive)		17	A
E_{AR}	Repetitive Avalanche Energy		0.5	Т
E_{AS}	Single Pulse Avalanche Energy		670	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

Electrical Characteristics (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 800V$			50	μΑ
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 14A$			150	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2mA$	2.1	3	3.9	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

Dynamic Characteristics (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V$		4507		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		2092		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		108		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		180		
Q_{gs}	Gate – Source Charge	$V_{\rm Bus} = 400 V$		22		nC
Q_{gd}	Gate – Drain Charge	$I_D = 28A$		90		
T _{d(on)}	Turn-on Delay Time	Inductive switching @125°C		10		
T_{r}	Rise Time	$V_{GS} = 15V$		13		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 533V$ $I_{\text{D}} = 28A$		83		ns
T_{f}	Fall Time	$R_G = 2.5\Omega$		35		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		486		Ţ
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 28A, R_G = 2.5\Omega$		278		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		850		Т
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 28A, R_G = 2.5\Omega$		342		μJ
R_{thJC}	Junction to Case Thermal Resistance				0.45	°C/W

Source - Drain diode ratings and characteristics (per super junction MOSFET)

Source Divings who end were proper june and the series								
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_S	Continuous Source current		$Tc = 25^{\circ}C$		28		Λ	
	(Body diode)		$Tc = 80^{\circ}C$		21		Α	
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -28A$				1.2	V	
dv/dt	Peak Diode Recovery					6	V/ns	
t_{rr}	Reverse Recovery Time	$I_S = -28A ; V_R = 400V$			550		ns	
Q_{rr}	Reverse Recovery Charge	$di_s/dt = 200A/\mu s$			30		μC	

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_{S} \leq \text{--} \ 28 A \qquad di/dt \leq 200 A/\mu s \qquad V_{R} \leq V_{DSS} \qquad T_{j} \leq 150^{\circ} C$



Thermal and package characteristics

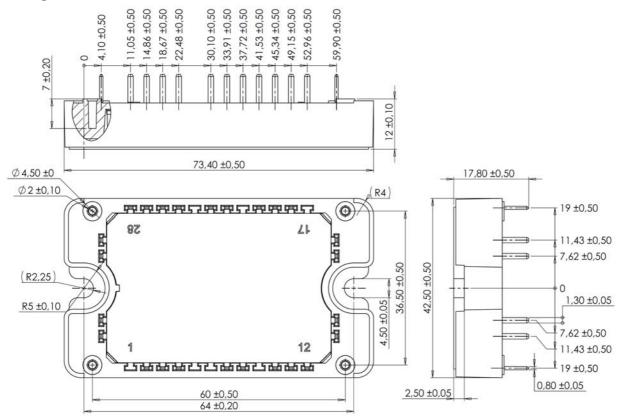
Symbol	Characteristic			Min	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance				0.45	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V
$T_{\rm J}$	Operating junction temperature range			-40	150	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$	= 298.15 K		3952		K
$\Delta B/B$		T _C =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

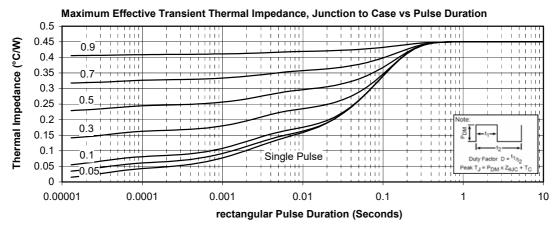
Package outline (dimensions in mm)



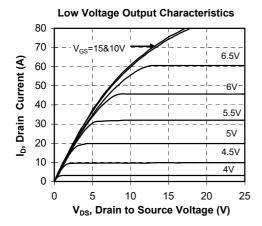
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

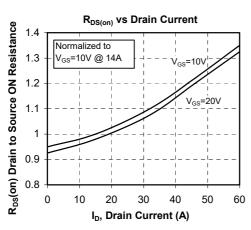


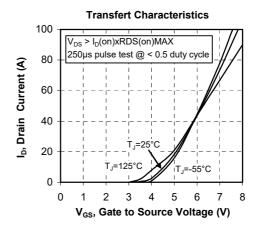
Typical Performance Curve

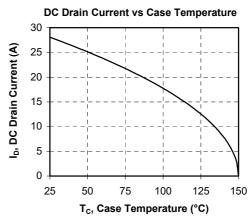


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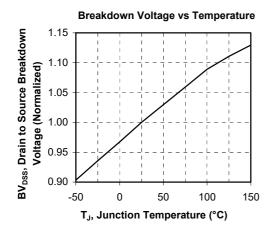


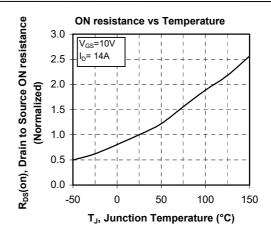


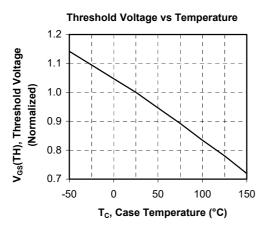


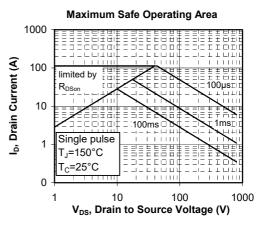


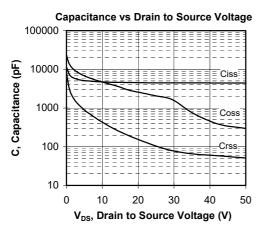


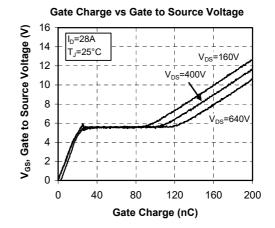






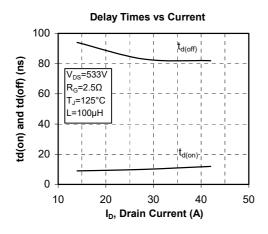


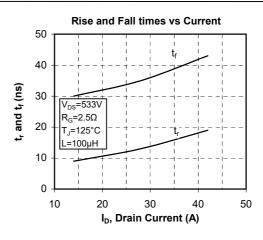


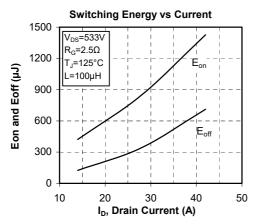


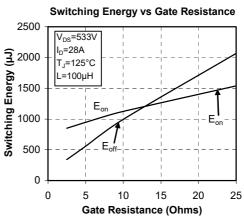
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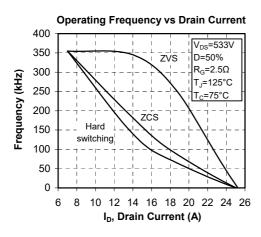


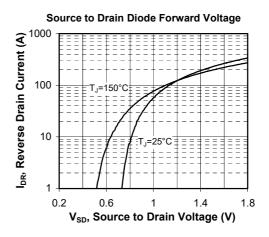












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